

# **Design and RF Measurements of** an X-band Accelerating Structure for the Sparc Project

INFN-LNF; UNIVERSITY OF ROME LA SAPIENZA; INFN - MI

## Presented by BRUNO SPATARO

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## SALAF (Strutture Acceleranti Lineari ad Alta Frequenza) is the INFN r&d programm on *"multicell resonating structures"* operating at X-band (10 ÷ 12 GHz).

### the MOTIVATION ......

To use in high brilliance photo-injectors *(SPARC-phase-2)* to compensate for the beam longitudinal phase-space distortion, enhanced by the bunch compression of the acceleration process

## To gain know-how in vacuum microwave technologies



## **Correction of the Phase-Space distortion**

- → The 4th harmonic structure provides RF curvature local correction.
- **Beam longitudinal emittance hold within limited values.**
- Minimum bunch length achieved.





## **SUMMARY of the ACTIVITY**

## ElectroMagnetic Design

Travelling or Standing Wave structure ?

Mode of operation ...  $\pi$  or  $\pi/2$  ?

## Hardware Design

**Construction of a 11.424 GHz Cu** *prototype* 

RF characterization

Development and test of a real model:

- ➔ precise machining
- → brazing
- vacuum tests
- → RF tests

E.M. DESIGN

Recent experiences (NLC) have been made at SLAC and KEK Travelling Wave X-band structures.



MultiMegawatts peak power tests, carried out at SLAC, had been showing frequent internal discharges caused by field



emission.

### ... TW structures

the fully matched condition of TW structures helps the RF generator in feeding the resonator under discharge .... and sustains the power flow throughout it.

 $\rightarrow$  hence, the inner surface may get damaged.

the design accelerating gradient (60 ÷ 70 MV/m) may not be achieved routinely.

To overcome the problem, instead of TW units, Standing Wave structures can be used. Internal discharges cause strong cavity detuning and generator mismatching.

**RF POWER FEEDING →** *IMPOSSIBLE* under discharge

... Standing Wave structure<mark>s</mark>

the Standing Wave accelerating section is a diskloaded guide with the output port *shorted*.



**R&D** aims to analyze in details ....

axially coupled  $\pi$  and  $\pi/2$  mode SW structures

and

 $2\pi/3$  and  $5\pi/6$  mode TW structures

Important R&D goals are ....

To study the accelerating structure sensitivity vs mechanical tolerances and assembling errors

To investigate the effects of the power dissipation on the general performances of the structure.

## E.M. design guide-lines of 11 GHz accelerating structures



To get high shunt impedance to reduce the need of RF po



To get high ratio  $E_0^2/W$  to optimize the efficiency of the st

To reduce accelerating structure sensitivity vs mechanical tolerances and assembling errors by increasing the group velocity (i.e. filling time)

To reduce the parasitic mode content which affect the beau dynamics

To shape the structure internal profile in order to avoid multipactoring discharges



## ... some basic expressions of the disk-loaded waveguide ...

Analytical expression of the dispersion curve:

$$\omega_{\phi}^{2} = \omega_{0}^{2} + 0.5 \cdot (\omega_{\pi}^{2} - \omega_{0}^{2}) \cdot (1 - \cos\phi)$$
Coupling  $K = (\__{\pi} -\__{0}) I_{\_\pi/2}$   $K = 2.42 \%$ 
Coupling coefficient:
(based upon geometric parameters)
Coupling  $K = \frac{\omega_{\pi} - \omega_{0}}{\omega_{\omega/2}} \approx ke^{-ch}$   $K = 2.27$ 
with  $k = \frac{4a^{3}}{3\pi J_{1}^{2}(2.405)b^{2}l} <<1$  and  $\alpha = \sqrt{\left(\frac{2.405}{a}\right)^{2} - \frac{\omega^{2}}{c^{2}}}$ 

... simulation of 9-cell  $\pi$ -mode ....

## DISPERSION CURVE vith and without beam-tubes





36406		
Frequency [MHz]	Mode [π]	
11152.818	0	
11162.906	1/8	
11191.717	1/4	
11235.333	3/8	
11287.522	1/2	
11340.448	5/8	
11386.000	3/4	
11416.834	7/8	
11427.704	1	

structure with mirrors

#### structure with tubes

Frequency [MHz]	Mode [p]
11160.784	1/9
11183.868	2/9
11219.481	1/3
11263.701	4/9
11311.225	5/9
11356.593	2/3
11393.989	7/9
11418.634	8/9
11427.465	1

## ... simulation of 9-cell $\pi$ -mode ...





### ... simulation of 9-cell $\pi$ -mode X-band structure with h = 3 mm





### ... simulation of 9-cell $\pi$ -mode ....

Thermal flux and temperature fields of the boundary region of a copper structure.

Study performed with the ANSYS- $code^{(TM)}$ .



### ... simulation of 9-cell *π*-mode .....

### Comparison of Standing-Wave X-BAND Structures with different disktickness

# RF parameter list calculated with SUPERFISH, OSCAR2D and ABC codes $\pi \mod \pi$

-Frequency, F (MHz)	11426*	11427*
-Length for calculation, L (cm)	11.81	11.81
-Beam tube length, 1 (cm)	3	3
-Cavity number, n <sub>b</sub>	9	9
-Ratio of phase to light velocity, v/c	1	1
-Structure periodicity, L, (cm)	1.3121	1.3121
-Beam hole radius, r (cm)	0.4	0.4
-Iris Thickness, t(cm)	0.3	0.2
-Transit time factor, T	0.739	0.731
-Factor of merit, Q	8069.46	8413.18
-Form factor, $R_{a}/Q$ ( $\Omega/m$ )	9232.34	9165.38
-Shunt impedance, R <sub>ab</sub> (MΩ/m)	74.5	77.11
- Coupling coefficient, K(%)	1.76	2.42
-Peak power, P (MW)	2.795	2.701
-Energy stored in cavity of length L, W (joules)	0.314	0.316
-Peak power per meter, P/m (MW/m)	23.66	22.87
-Energy stored in cavity per meter, W/m (joules/m)	2.659	2.677
-Duty cycle, D.C.	10-4	10-4
-Repetition frequency, f (Hz)	50	50
-Power dissipation, P, (Watt)	279.5	270.1
-Average accelerating field, E_(MV/m)	42	42
-Peak axial electric field, Error (MV/m)	56.84	57.49
-Kilpatrick factor	1.089	1.197
-Peak surface electric field, Ear (MV/m)	95.36	104.84
-Ratio of peak to average fields Emm/Emm	1.35	1.37
-Ratio of peak to average fields Ear/East	2.27	2.496
-Ratio of peak fields Bms/Em(mT/MV/m)	1.89	1.65
-Pulse charge, C (nC)	1	1
-Pulse length, t (psec)	10	10
- Number of bunches, n	1	1
-Average beam power, Phone (W)	0.248	0.248
-Energy spread due to the beam loading, %	$\pm 0.788$	$\pm 0.783$
-Loss parameters due to the HOM's K, (V/pC)	17.77	16.95
-Loss parameter of the operating mode, Ko(V/pC)	19.57	19.43

\* Mesh 0.03 cm. With a mesh of 0.01 cm, we have too long calculation time, but we have seen that the frequency value converge to 11424 MHz.









### CONSTRUCTION of a $\pi$ -MODE STANDING-WAVE 11.4 GHz COPPER PROTOTYPE





## ASSEMBLED X-BAND MODEL



## CHARACTERIZATION OF THE X-BAND STANDING-WAVE COPPER MOD





#### BEHAVIOUR OF OTHER LONGITUDINAL E-FIELD FUNDAMENTAL MODES









-BAND COPPER PROTOTYPE MAIN PARAMETERS				
$\pi$ -mode frequency	11.424 GHz			
Form factor r/Q	9400 Ω/m ( <i>9165</i> )			
Unloaded Q	7960 ( <del>8413</del> )	In red, the theoretical values		
External Q	8000			
E-Field flatness	<1%			
Number of cells	9			
Structure length	110 mm			

## CONCLUSIONS

- FIRST R&D ACTIVITY on X-BAND STANDING WAVE DISK-LOADED STRUCT STARTED SUCCESSFULLY.
- IMPORTANT KNOW-HOW ASPECTS of the E.M DESIGN and FABRICATION of X-BAND ACCELERATING SECTIONS HAVE BEEN ACQUIRED

**FUTURE ACTIVITY**:

CARRY OUT BRAZING PROCESS to VERIFY the VACUUM PERFORMANCES of a CAVITY

 $\square$ 

DEVELOPE a  $\pi/2$ -MODE STRUCTURE TO CHE.M. SENSITIVITY vs FABRICATION ERROR